

TMR1162

Nano-Ampere TMR Unipolar Switch

General Description

The TMR1162 is a 200nA ultra-low power magnetic switch sensor. It is a unipolar magnetic switch that integrates TMR and CMOS technology in order to provide a magnetically triggered digital switch with high sensitivity, high speed, and ultra-low power consumption. It integrates a push-pull half-bridge TMR magnetic sensor and CMOS signal processing circuitry within the same package. Designed for use in applications that are both power-critical and performance-demanding, this device includes an on-chip TMR voltage generator for precise magnetic sensing, TMR voltage amplifier and comparator, a Schmitt trigger to provide switching hysteresis for noise rejection, and open-drain output. An internal band gap regulator is used to provide temperature compensated supply voltage for internal circuits, and it allows a wide range of operating supply voltages. The TMR1162 features ultra-low power consumption at 200nA with a fast internal switching frequency at 50Hz. Other important features include accurate switching points, excellent thermal stability, and a wide range of supply voltages. It is available in two packaging form factors: SOT23-3 (P/N TMR1162S), or TO-92S (P/N TMR1162T).

Features and Benefits

- Tunneling Magnetoresistance (TMR) Technology
- Nano-Ampere Ultra-low Power Consumption at 200nA
- Fast Internal Switching Frequency at 50Hz
- Unipolar Operation with High Sensitivity
- Operating Temperature Range from -40°C to 125°C
- Wide Range of Supply Voltages from 1.8V to 5.5V
- Open-drain Output

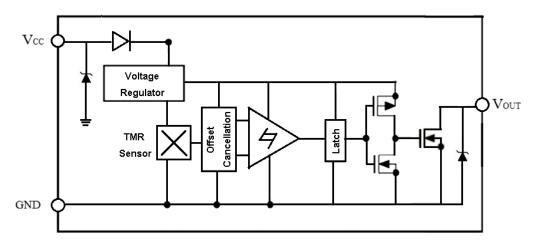
Applications

- Utility Meters including Water, Gas, and Heat Meters
- Speed Sensing and Position Sensing
- Motor and Fan Control
- Power Window

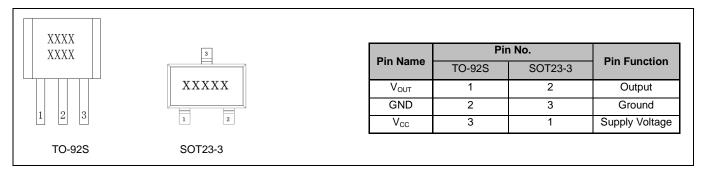


TMR1162S (Left), TMR1162T (Right)

Block Diagram



Pin Configuration



Absolute Maximum Ratings

| Characteristic | Symbol | Rating | Units |
|-------------------------------|----------------------|-----------------|-------|
| Supply Voltage | V _{CC} | 7 | V |
| Reverse Supply Voltage | V_{RCC} | 0.3 | V |
| Output Current | I _{OUTSINK} | 20 | mA |
| Magnetic Flux Density | В | 4000 | G |
| ESD Level (HBM) | V_{ESD} | 4 | kV |
| Operating Ambient Temperature | T _A | - 40∼125 | °C |
| Storage Temperature | T _{stg} | - 50∼150 | °C |

Electrical Characteristics (V_{CC}=3.0V, T_A=25°C)

| Characteristic | Symbol | Test Conditions | Min. | Тур. | Max. | Units |
|----------------------------|---------------------|--|------|------|------|-------|
| Supply Voltage | V _{CC} | Operating | 1.8 | 3.0 | 5.5 | V |
| Output Stress Voltage | V _{stress} | | | | 5.5 | V |
| Output leak Current | I _{leak} | OUT=High, V _{cc} =3V, V _{out} =3V | | | 1 | μA |
| Output Turn-off Resistance | R _{off} | OUT=High | | 10 | | МΩ |
| Output Low Voltage | V _{ol} | OUT=Low, V _{cc} =3V, I _{sink} =3mA | | | 0.1 | V |
| Output Turn-on Resistance | R _{on} | OUT=Low | | | 10 | Ω |
| Supply Current | I _{cc} | Output open | | 200 | | nA |
| Switching Frequency | F | | | 50 | | Hz |

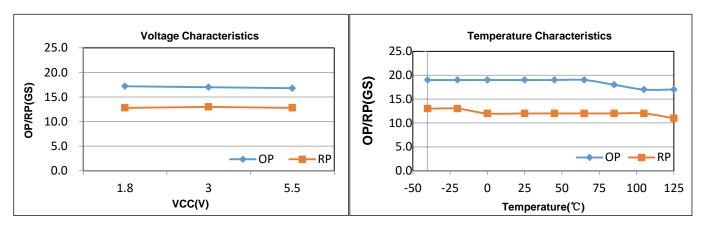
Note: A 1kOhm pull-up resistor is connected between VCC and VOUT, and a 0.1µF capacitor is connected between VCC and GND during all tests in the table above.

Magnetic Characteristics ($V_{CC} = 3.0V$, $T_A = 25$ °C)

| Characteristic | Symbol | Min. | Тур. | Max. | Units |
|----------------|-----------------|------|------|------|-------|
| Operate Point | B _{OP} | | 17 | | G |
| Release Point | B_RP | | 13 | | G |
| Hysteresis | B _H | | 4 | | G |

Note: A 1kOhm pull-up resistor is connected between VCC and VOUT, and a 0.1µF capacitor is connected between VCC and GND during all tests in the table above.

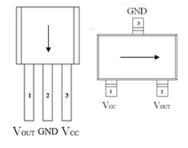
Voltage and Temperature Characteristics



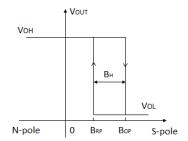
Output Behavior vs. Magnetic Polarity

| Magnetic Polarity | Test Conditions | Output | |
|------------------------------|---------------------|------------|--|
| South Pole for TO92 Package | B > B _{OP} | Low (On) | |
| | B < B _{RP} | High (Off) | |
| North Pole for SOT23 Package | B > B _{OP} | Low (On) | |
| | B < B _{RP} | High (Off) | |

Note: The output is "High" when power is turned on under zero magnetic field.



Sensing Direction

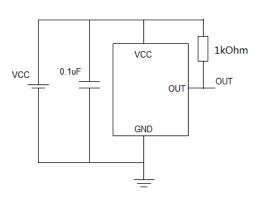


Switching Behavior of TMR1162

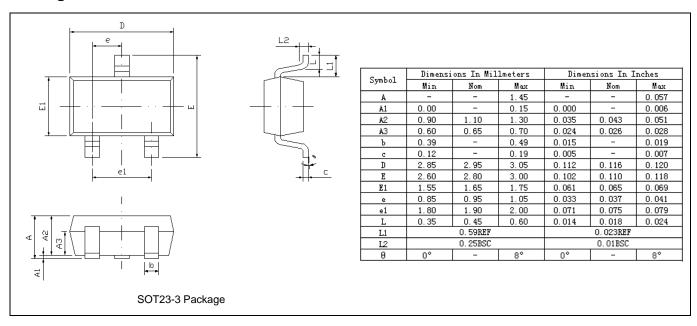
Application Information

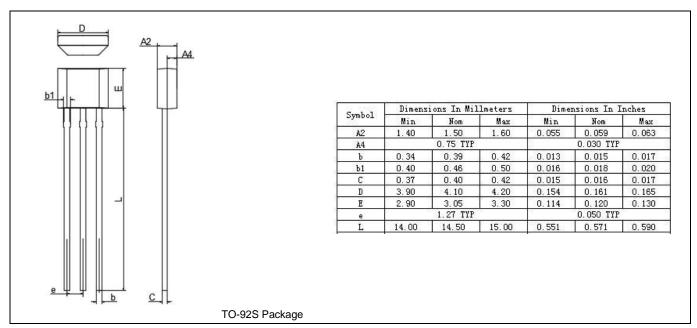
The output of the TMR1162 switches low (turns on) when a magnetic field parallel to the TMR sensor exceeds the operate point threshold, B_{OP} . When the magnetic field is reduced below the release point, B_{RP} , the device output goes high (turns off). The difference between the magnetic operate point and release point is the hysteresis B_H of the device.

It is strongly recommended that an external bypass capacitor be connected in close proximity to the device between the supply and ground to reduce noise. The typical value of the external capacitor is $0.1\mu F$.

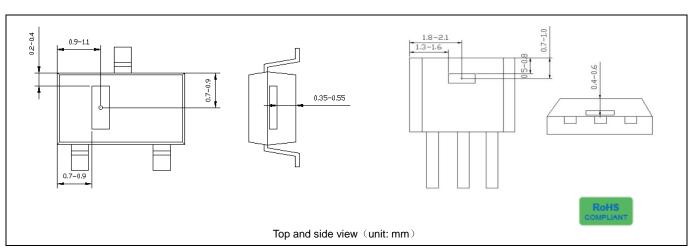


Package Information





TMR Sensor Position





MultiDimension Technology Co., Ltd.

Address: No.7 Guangdong Road, Zhangjiagang Free Trade Zone, Jiangsu, 215634, China

Web: www.dowaytech.com/en Email: info@dowaytech.com

The information provided herein by MultiDimension Technology Co., Ltd. (hereinafter MultiDimension) is believed to be accurate and reliable. Publication neither conveys nor implies any license under patent or other industrial or intellectual property rights. MultiDimension reserves the right to make changes to product specifications for the purpose of improving product quality, reliability, and functionality. MultiDimension does not assume any liability arising out of the application and use of its products. MultiDimension's customers using or selling this product for use in appliances, devices, or systems where malfunction can reasonably be expected to result in personal injury do so at their own risk and agree to fully indemnify MultiDimension for any damages resulting from such applications.